

## Converter Thyristor Type N1463xx36xxx to N1463xx42xxx

### Absolute maximum ratings

|           | VOLTAGE RATINGS                                  | MAXIMUM LIMITS | UNITS |
|-----------|--|----------------|-------|
| $V_{DRM}$ | Repetitive peak off-state voltage, (note 1).     | 3600-4200      | V     |
| $V_{DSM}$ | Non-repetitive peak off-state voltage, (note 1). | 3600-4200      | V     |
| $V_{RRM}$ | Repetitive peak reverse voltage, (note 1).       | 3600-4200      | V     |
| $V_{RSM}$ | Non-repetitive peak reverse voltage, (note 1).   | 3700-4300      | V     |

|               | RATINGS   | MAXIMUM LIMITS     | UNITS       |
|---------------|---|--------------------|-------------|
| $I_{T(AV)}$   | Mean on-state current, $T_{sink}=55^{\circ}C$ , (note 2).                   | 2850               | A           |
| $I_{T(AV)}$   | Mean on-state current. $T_{sink}=85^{\circ}C$ , (note 5).                   | 1960               | A           |
| $I_{T(AV)}$   | Mean on-state current. $T_{sink}=85^{\circ}C$ , (note 3).                   | 1200               | A           |
| $I_{T(RMS)}$  | Nominal RMS on-state current, $25^{\circ}C$ , (note 2).                     | 5590               | A           |
| $I_{T(d.c.)}$ | D.C. on-state current, $25^{\circ}C$ , (note 7).                            | 4900               | A           |
| $I_{TSM}$     | Peak non-repetitive surge $t_p=10ms$ , $V_{RM}=0.6V_{RRM}$ , (note 4).      | $46.8 \times 10^3$ | A           |
| $I_{TSM2}$    | Peak non-repetitive surge $t_p=10ms$ , $V_{RM} \leq 10V$ , (note 4).        | $52.0 \times 10^3$ | A           |
| $I^2t$        | $I^2t$ capacity for fusing $t_p=10ms$ , $V_{RM}=0.6V_{RRM}$ , (note 4).     | $11.0 \times 10^6$ | $A^2s$      |
| $I^2t$        | $I^2t$ capacity for fusing $t_p=10ms$ , $V_{RM} \leq 10V$ , (note 4).       | $13.5 \times 10^6$ | $A^2s$      |
| $I^2t$        | $I^2t$ capacity for fusing $t_p=3ms$ , $V_{RM} \leq 0.6V_{RRM}$ , (note 4). | $8.2 \times 10^6$  | $A^2s$      |
| $di/dt$       | Critical rate of rise of on-state current (continuous), (note 6).           | 150                | $A/\mu s$   |
| $di/dt$       | Critical rate of rise of on-state current (intermittent), (note 6).         | 300                | $A/\mu s$   |
| $I_{FGM}$     | Peak forward gate current.  | 10                 | A           |
| $V_{RGM}$     | Peak reverse gate voltage.  | 5                  | V           |
| $P_{G(AV)}$   | Mean forward gate power.  | 5                  | W           |
| $P_{GM}$      | Peak forward gate power.  | 30                 | W           |
| $V_{GD}$      | Non-trigger gate voltage, (Note 5).   | 0.25               | V           |
| $T_{HS}$      | Operating temperature range.  | -40 to +125        | $^{\circ}C$ |
| $T_{stg}$     | Storage temperature range.  | -40 to +150        | $^{\circ}C$ |

#### Notes:-

- 1) De-rating factor of 0.13% per K is applicable for  $T_j$  below  $25^{\circ}C$ .
- 2) Doubleside cooled, single phase; 50Hz,  $180^{\circ}$  half-sinewave.
- 3) Singleside cooled, single phase; 50Hz,  $180^{\circ}$  half-sinewave.
- 4) Half-sinewave,  $125^{\circ}C$   $T_j$  initial.
- 5) Rated  $V_{DRM}$ .
- 6)  $V_D=67\%V_{DRM}$ ,  $I_T=5500A$ ,  $I_{FG}=2A$ ,  $t_r=500ns$ .
- 7) Doubleside cooled.

**Characteristics**

|            | CHARACTERISTICS                             | MIN | TYP  | MAX  | TEST CONDITIONS                            | UNITS      |
|------------|---|-----|------|------|--|------------|
| $V_{TM}$   | Maximum peak on-state voltage.              | -   | -    | 1.87 | $I_T=5000A$ .                              | V          |
| $V_0$      | Threshold voltage.                          | -   | -    | 0.97 |  | V          |
| $R_T$      | Slope resistance.                           | -   | -    | 0.18 |  | m $\Omega$ |
| dv/dt      | Critical rate of rise of off-state voltage. | 200 | 1000 | 2000 | $V_D=80\% V_{DRM}$ .                       | V/ $\mu$ s |
| $I_{DRM}$  | Peak off-state current.                     | -   | -    | 250  | Rated $V_{DRM}$ ' (note 2).                | mA         |
| $I_{RRM}$  | Peak reverse current.                       | -   | -    | 250  | Rated $V_{RRM}$ ' (note 2).                | mA         |
| $V_{GT}$   | Gate trigger voltage                        | -   | -    | 3.0  | $T_J=25^\circ C$ .                         | V          |
| $I_{GT}$   | Gate trigger current                        | -   | -    | 300  | $T_J=25^\circ C$ . $V_D=10V$ ,<br>$I_A=3A$ | mA         |
| $I_H$      | Holding current                             | -   | -    | 1000 | $T_J=25^\circ C$ .                         | mA         |
| $R_\theta$ | Thermal resistance junction to sink.        | -   | -    | 11   | Double side cooled.                        | K/KW       |
|            |   | -   | -    | 22   | Single side cooled.                        | K/KW       |
| F          | Mounting force.                             | 63  | -    | 77   |  | kN         |
| $W_t$      | Weight.                                     | -   | 1.23 | -    |  | kg         |

## Notes:-

- 1) Unless otherwise indicated  $T_J=125^\circ C$ .
- 2) Leakage current limit, this will be increased in the future to 400mA

## Notes on Ratings and Characteristics

### 1 Voltage Grade Table

| Voltage Grade 'H' | $V_{DSM}$<br>$V_{DRM}$<br>$V_{RRM}$<br>V | $V_{RSM}$<br>V | $V_D$ $V_R$<br>$V_{DC}$ |
|-------------------|--|----------------|-------------------------|
| 36                | 3600                                     | 3700           | 2160                    |
| 37                | 3700                                     | 3800           | 2220                    |
| 38                | 3800                                     | 3900           | 2280                    |
| 39                | 3900                                     | 4000           | 2340                    |
| 40                | 4000                                     | 4100           | 2400                    |
| 41                | 4100                                     | 4200           | 2460                    |
| 42                | 4200                                     | 4300           | 2520                    |

### 2 Extension of Voltage Grades

This report is applicable to other and higher voltage grades when supply has been agreed by Sales/Production.

### 3 De-rating Factor

A blocking voltage de-rating factor of 0.13% per °C is applicable to this device for  $T_J$  below 25 °C.

### 4 Repetitive dv/dt

Higher dv/dt selections are available up to 2000V/μs on request.

### 5 Computer modelling parameters

#### 5.1 Device dissipation calculations

$$I_{AV} = \frac{-V_o + \sqrt{V_o^2 + 4 \cdot ff^2 \cdot r_s \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_s}$$

Where  $V_o = 0.97$  V,  $r_s = 0.180$ mΩ

$$W_{AV} = \frac{\Delta T}{R_{th}} \quad \Delta T = T_{jMax} - T_{Hs}$$

$R_{th}$  = Supplementary thermal impedance, see table below.

$ff$  = Form factor, see table below.

| Supplementary Thermal Impedance (at 50Hz operating frequency) |               |                |                  |        |
|---|---------------|----------------|------------------|--------|
| Conduction Angle  | 6 phase (60°) | 3 phase (120°) | Half wave (180°) | d.c.   |
| Square wave Double Side Cooled                                | 0.0118        | 0.0115         | 0.0112           | 0.0110 |
| Square wave Single Side Cooled                                | 0.0236        | 0.0230         | 0.0224           | 0.0220 |
| Sine wave Double Side Cooled                                  | 0.0116        | 0.0112         | 0.0101           |        |
| Sine wave Single Side Cooled                                  | 0.0232        | 0.0224         | 0.0202           |        |

| Form Factors     |      |      |      |      |
|------------------|------|------|------|------|
| Conduction Angle | 60°  | 120° | 180° | d.c. |
| Square wave      | 2.45 | 1.73 | 1.41 | 1    |
| Sine wave        | 2.78 | 1.88 | 1.57 |      |

## 5.2 Calculating $V_T$ using ABCD coefficients

The on-state characteristic  $I_T$  vs  $V_T$ , on Fig. 9, is represented in two ways; (i) the well established  $V_0$  and  $r_S$  tangent and (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for  $V_T$  in terms of  $I_T$  given below:

$$V_T = A + B \cdot \ln(I_T) + C \cdot I_T + D \cdot \sqrt{I_T}$$

The constants, derived by curve fitting software, are given in this report for both hot and cold characteristics where possible. The resulting values for  $V_T$  agree with the true device characteristic over a current range, which is limited to that plotted.

| 125°C Coefficients |                         | 25°C Coefficients |                         |
|--------------------|-------------------------|-------------------|-------------------------|
| A                  | $9.70 \times 10^{-01}$  | A                 | $1.10 \times 10^{00}$   |
| B                  | $1.06 \times 10^{-03}$  | B                 | $1.21 \times 10^{-02}$  |
| C                  | $1.80 \times 10^{-04}$  | C                 | $1.44 \times 10^{-04}$  |
| D                  | $-1.01 \times 10^{-14}$ | D                 | $-1.21 \times 10^{-03}$ |

## 5.3 D.C. Thermal impedance calculation

$$r_t = \sum_{p=1}^{p=n} r_p \left( 1 - e^{-\frac{t}{\tau_p}} \right)$$

Where  $p = 1$  to  $n$ ,  $n$  is the number of terms in the series.

$t$  = Duration of heating pulse in seconds.

$r_t$  = Thermal resistance at time  $t$ .

$r_p$  = Amplitude of  $p_{th}$  term.

$\tau_p$  = Time Constant of  $r_{th}$  term.

| D.C. Double Side Cooled |                         |                         |                         |                         |
|-------------------------|-------------------------|-------------------------|-------------------------|-------------------------|
| Term                    | 1                       | 2                       | 3                       | 4                       |
| $r_p$                   | $5.214 \times 10^{-03}$ | $1.901 \times 10^{-03}$ | $2.560 \times 10^{-03}$ | $8.720 \times 10^{-04}$ |
| $\tau_p$                | $9.882 \times 10^{-01}$ | $3.481 \times 10^{-01}$ | $1.147 \times 10^{-01}$ | $8.180 \times 10^{-03}$ |

| D.C. Single Side Cooled |     |     |     |     |     |
|-------------------------|-----|-----|-----|-----|-----|
| Term                    | 1   | 2   | 3   | 4   | 5   |
| $r_p$                   | N/A | N/A | N/A | N/A | N/A |
| $\tau_p$                | N/A | N/A | N/A | N/A | N/A |

Curves

Figure 1, Maximum on-state characteristic

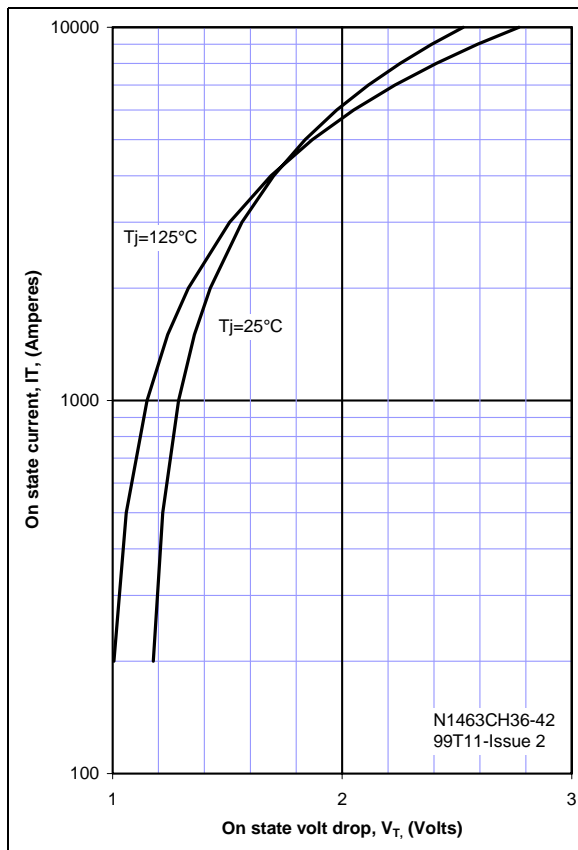


Figure 2, Transient thermal impedance

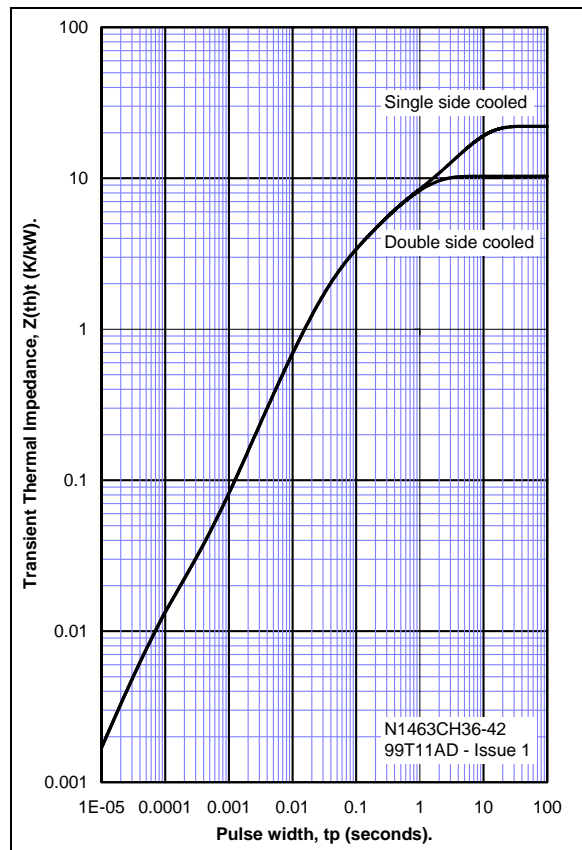


Figure 3, Maximum non repetitive surge

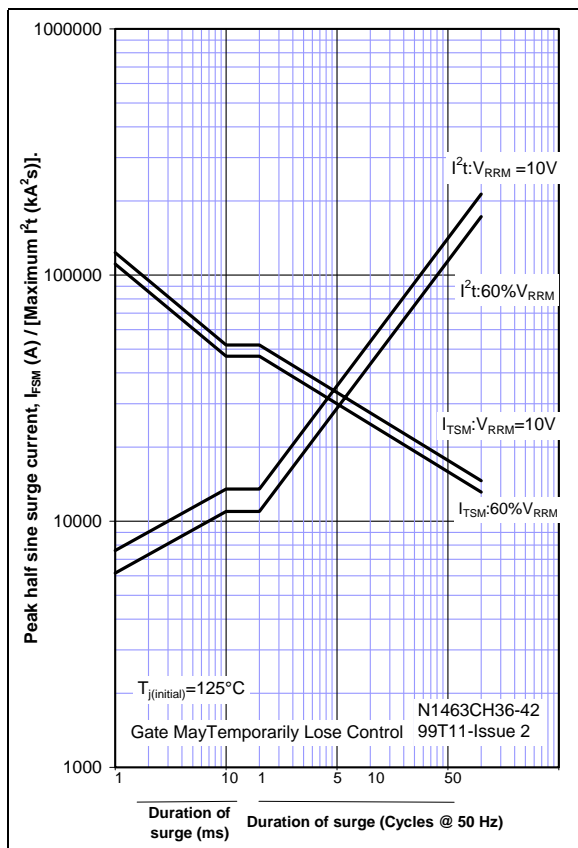
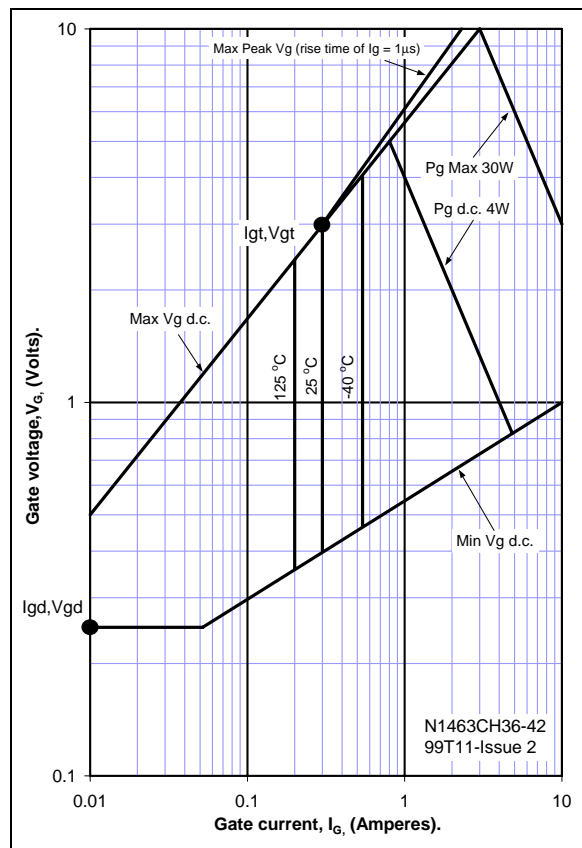
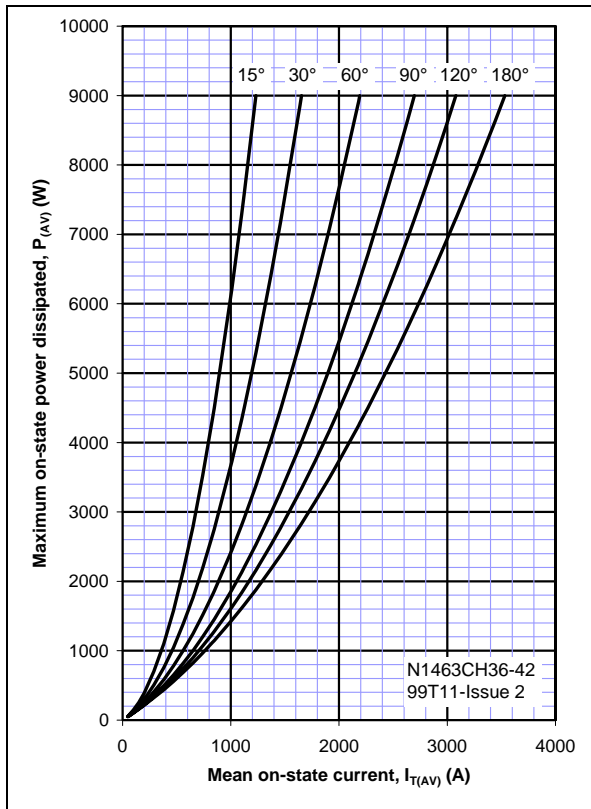


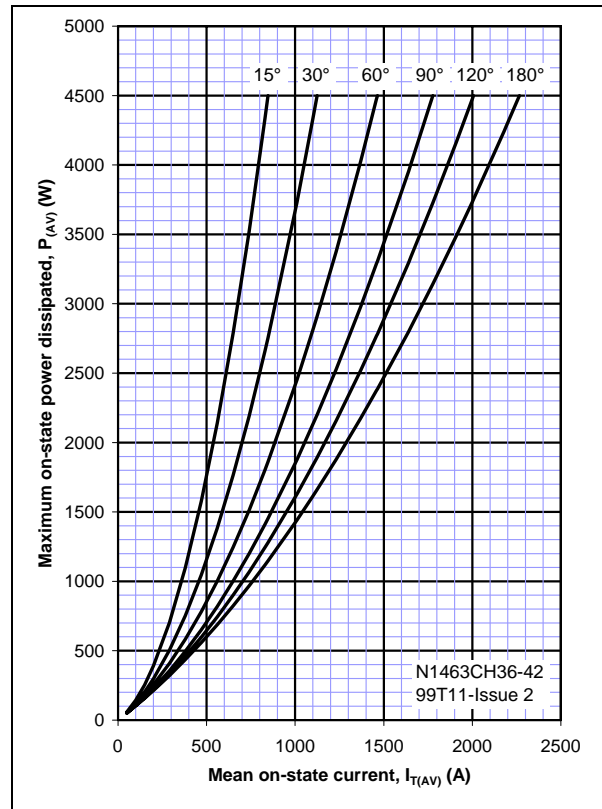
Figure 4, Gate characteristics, 25°C



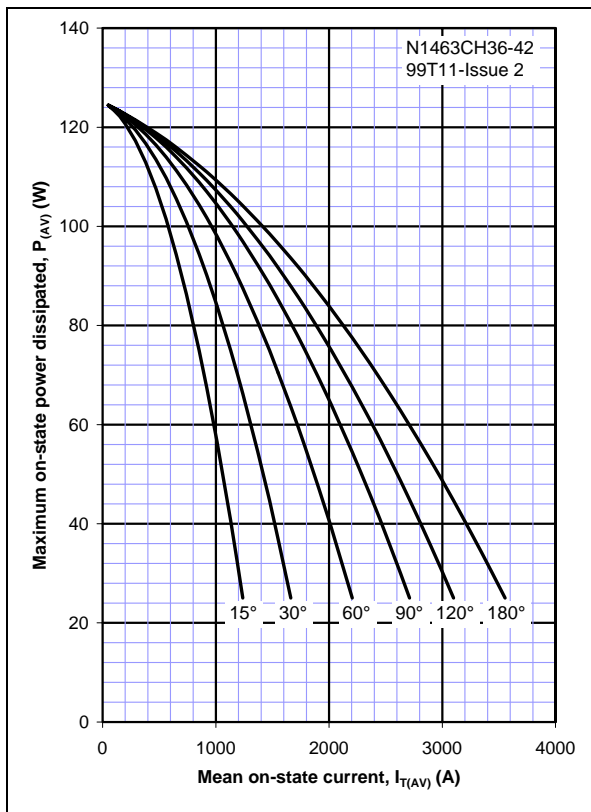
**Figure 5, Power dissipation vs. mean current, sinewave, double side cooled**



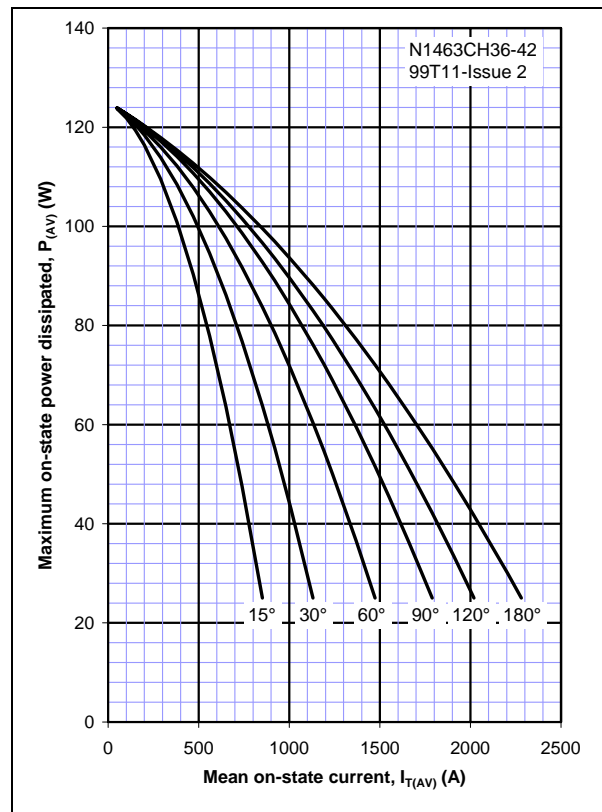
**Figure 6, Power dissipation vs. mean current, sinewave, single side cooled**



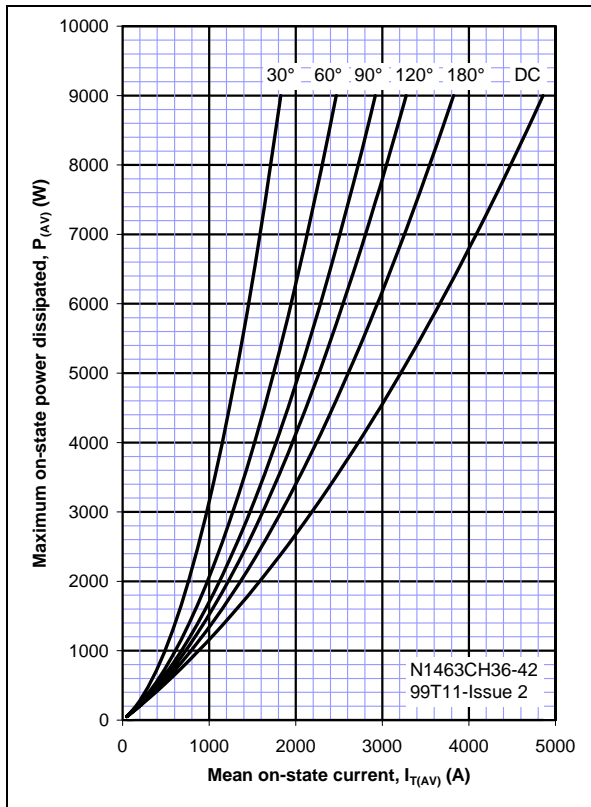
**Figure 7, Heatsink temperature vs. mean current, sinewave, double side cooled**



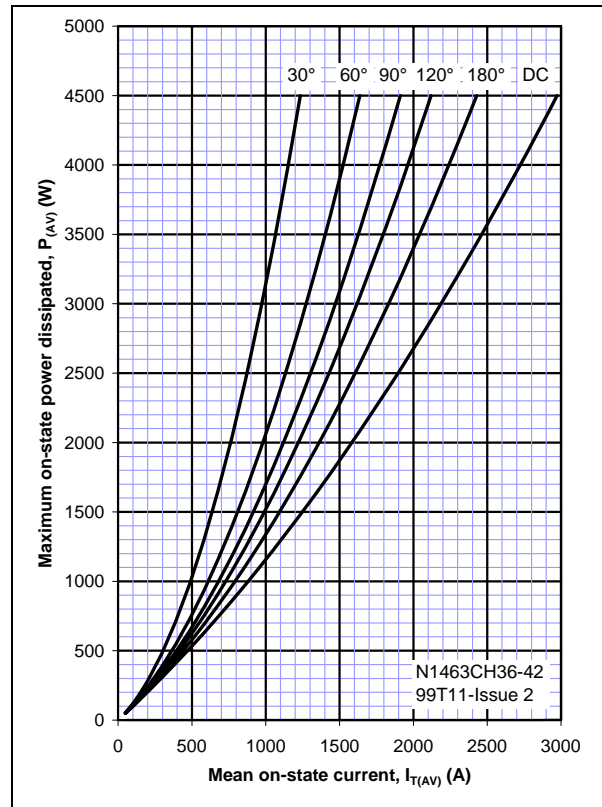
**Figure 8, Heatsink temperature vs. mean current, sinewave, single side cooled**



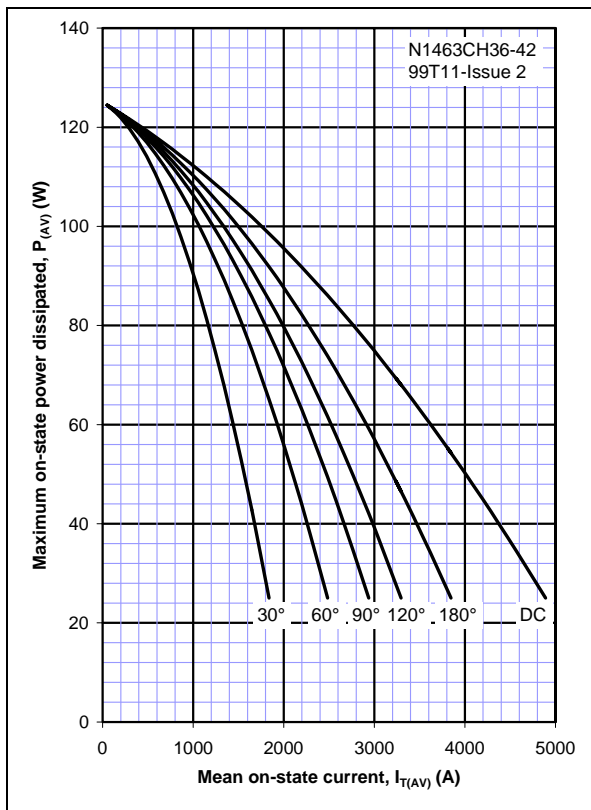
**Figure 9, Power dissipation vs. mean current, squarewave, double side cooled**



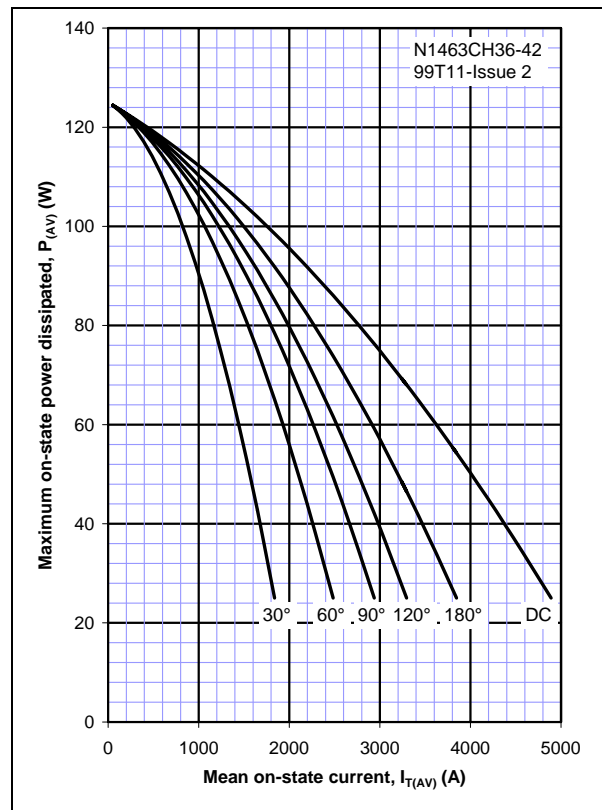
**Figure 10, Power dissipation vs. mean current, squarewave, single side cooled**



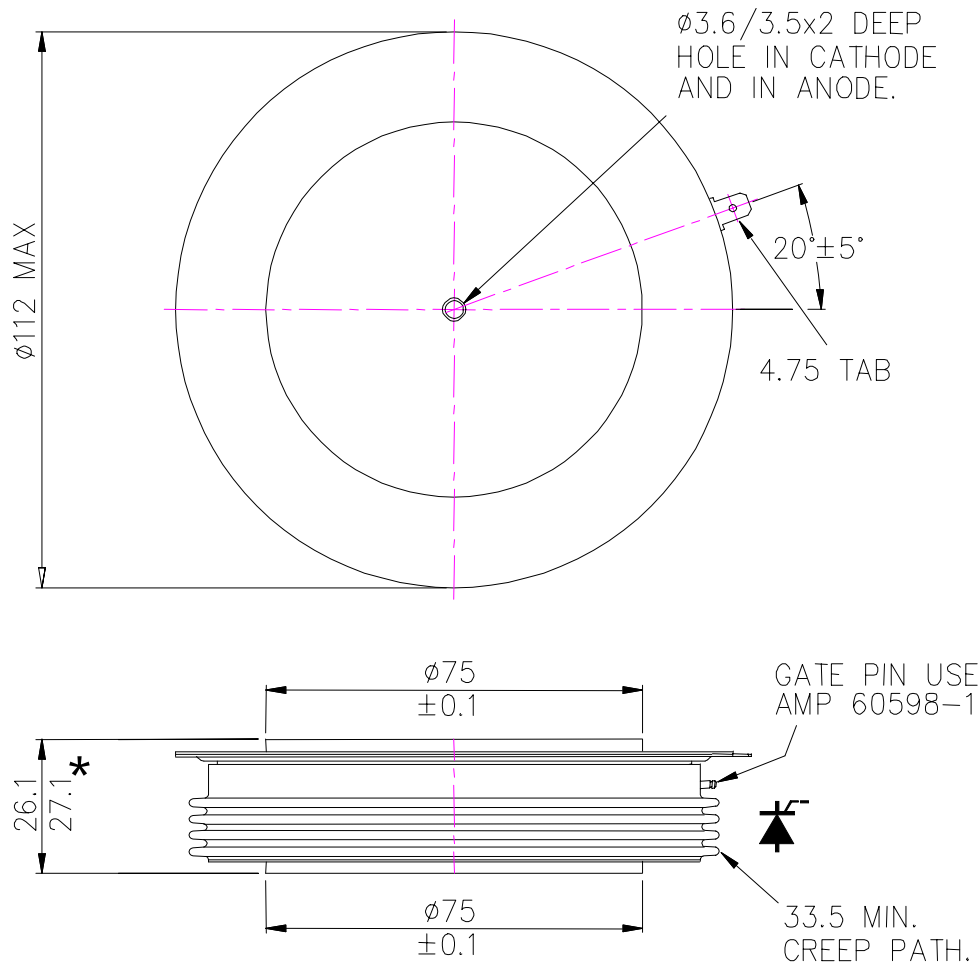
**Figure 11, Heatsink temperature vs. mean current, squarewave, double side cooled**



**Figure 12, Heatsink temperature vs. mean current, squarewave, single side cooled**



Outline drawing & ordering information



\* Also available in 36mm height  
[Standard for  $V_{RRM} > 5.2$  kV]

101A325

ORDERING INFORMATION

(Please quote 12 digit code as below)

|                 |                 |                        |                                 |                       |                      |                     |
|-----------------|-----------------|------------------------|---------------------------------|-----------------------|----------------------|---------------------|
| <b>N1063</b>    | ◆               | ◆                      | ◆ ◆                             | ◆ ◆ ◆                 |                      |                     |
| Fixed Type Code | Outline Code    |                        | Voltage Code<br>$V_{DRM} / 100$ | dv/dt Code            |                      |                     |
|                 | C – 26mm Height | H – standard explosion |                                 | Blank = 200V/ $\mu$ s | GOO = 300V/ $\mu$ s  | HOO = 400V/ $\mu$ s |
|                 | D – 36mm Height | Z – enhanced explosion | JOO = 500V/ $\mu$ s             | KOO = 750V/ $\mu$ s   | LOO = 1000V/ $\mu$ s |                     |

Typical order code : N1463CZ42 – 4.2kV  $V_{DRM}$ , 26mm high, enhanced explosion rating capsule thyristor

**WESTCODE**

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